

SHINDENGEN

General Purpose Rectifiers

SIL Bridges

D2SB80

800V 1.5A

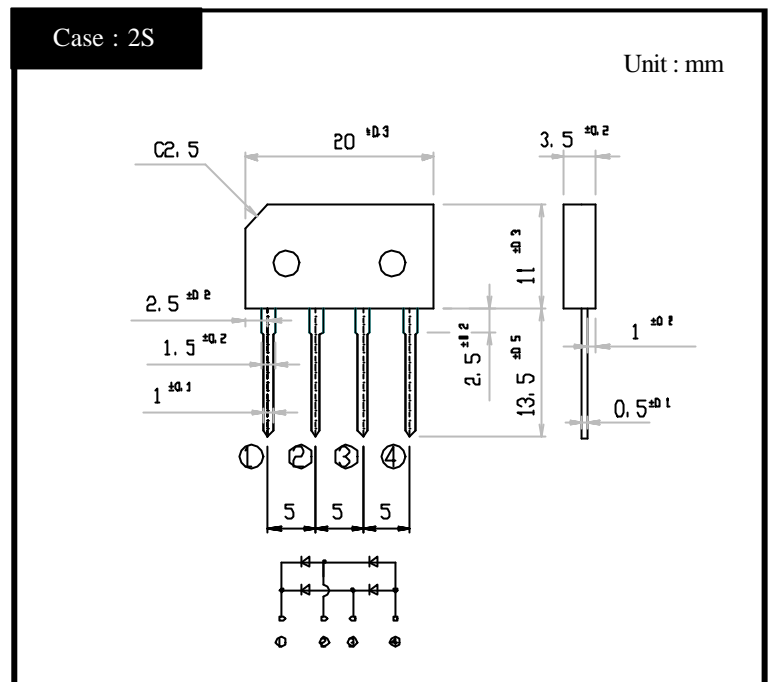
FEATURES

- Thin Single In-Line Package
- High IFSM
- Applicable to Automatic Insertion

APPLICATION

- Switching power supply
- Home Appliances, Office Equipment
- Telecommunication, Factory Automation

OUTLINE DIMENSIONS



RATINGS

Absolute Maximum Ratings (If not specified T_I=25)

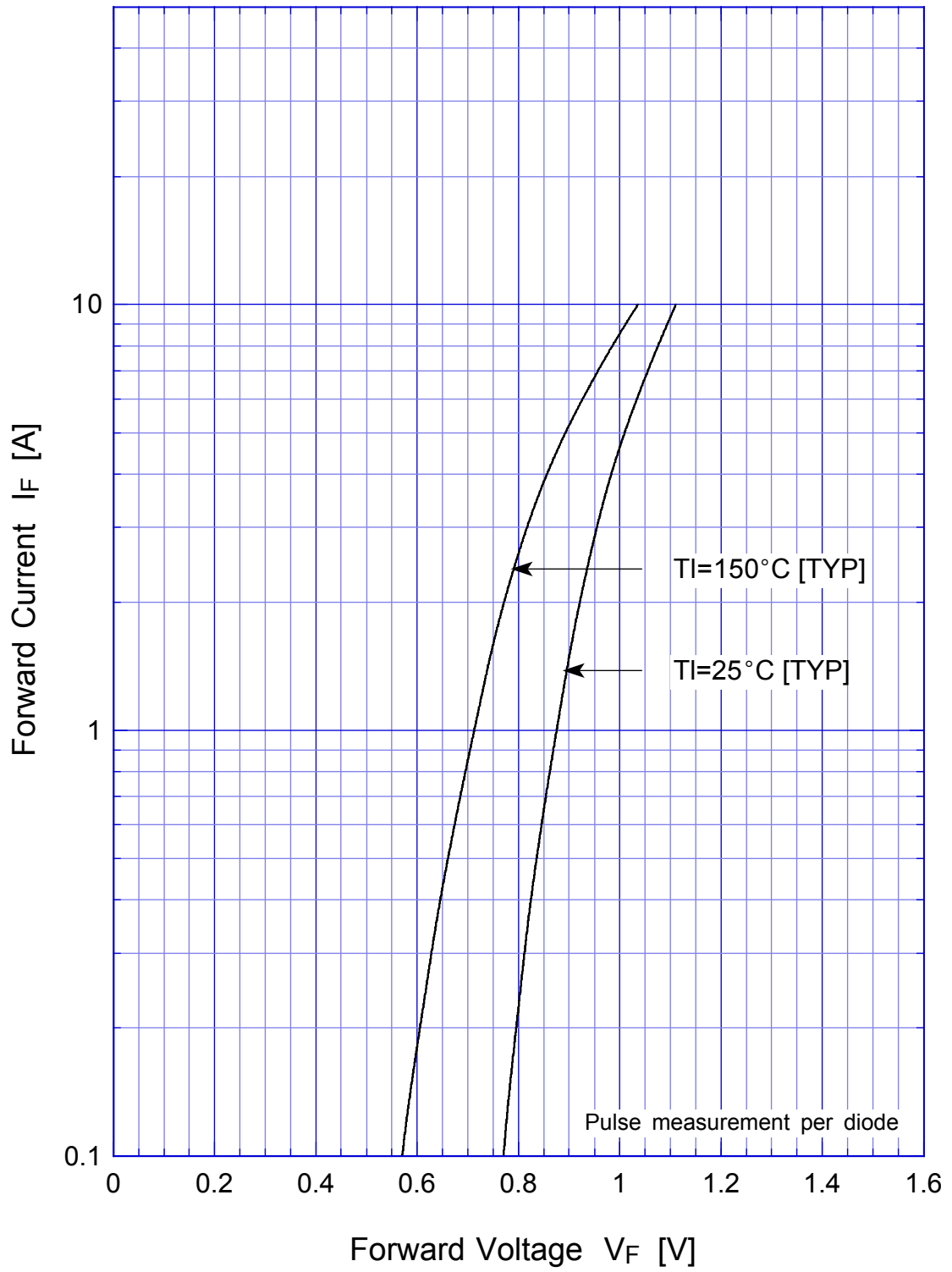
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-40 ~ 150	
Operating Junction Temperature	T _j		150	
Maximum Reverse Voltage	V _{RM}		800	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, On glass-epoxy substrate, T _a =25	1.5	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, T _j =25	80	A
Current Squared Time	I ² t	2ms t < 10ms T _j =25	32	A ² s

Electrical Characteristics (If not specified T_I=25)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	I _F =0.75A, Pulse measurement, Rating of per diode	Max. 1.05	V
Reverse Current	I _R	V _R =V _{RM} , Pulse measurement, Rating of per diode	Max. 10	μA
Thermal Resistance	j-l	junction to lead	Max. 10	/W
	j-a	junction to ambient	Max. 47	

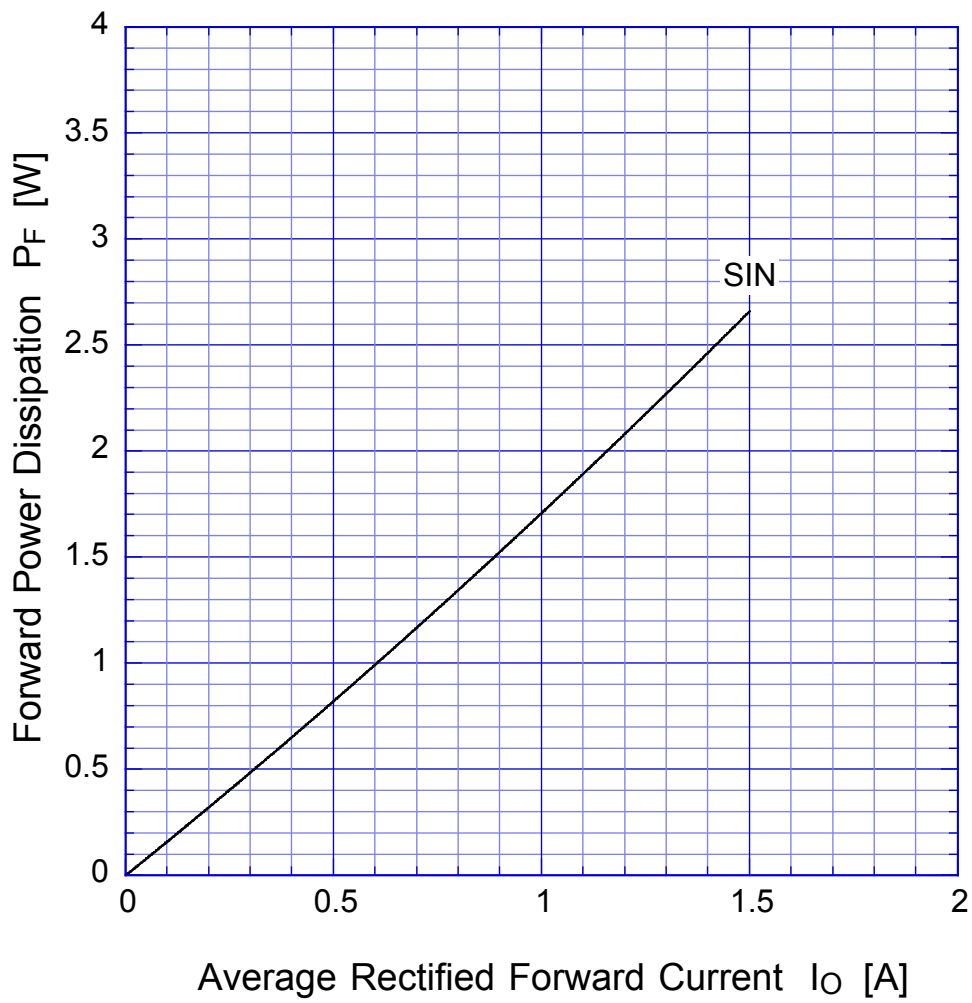
D2SBx

Forward Voltage



D2SBx

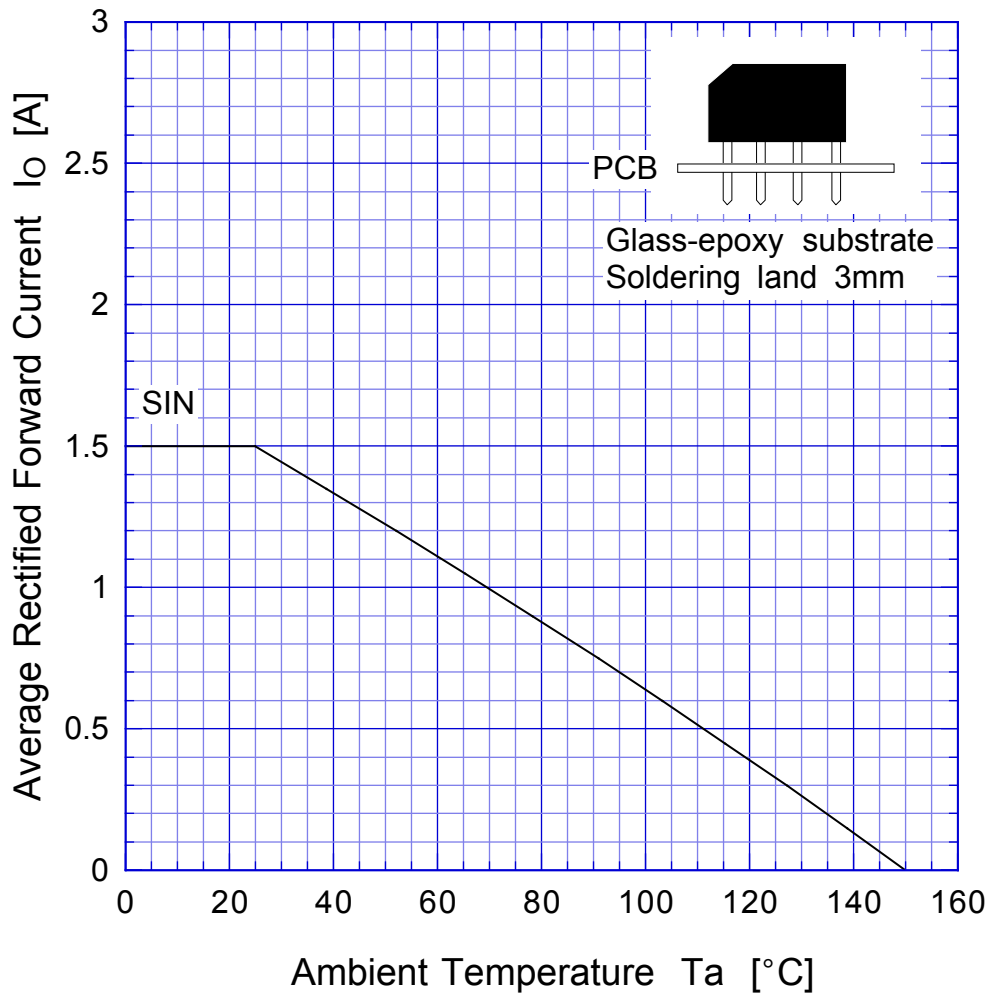
Forward Power Dissipation



$T_j = 150^\circ\text{C}$
Sine wave

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Derating Curve



Sine wave
R-load
Free in air

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Peak Surge Forward Capability

